



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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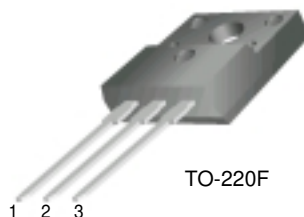
FYPF1004DN

Features

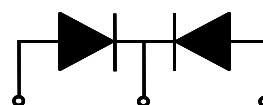
- Low forward voltage drop
- High frequency properties and switching speed
- Guard ring for over-voltage protection

Applications

- Switched mode power supply
- Freewheeling diodes



TO-220F



1. Anode 2. Cathode 3. Anode

SCHOTTKY BARRIER RECTIFIER

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	40	V
V_R	Maximum DC Reverse Voltage	40	V
$I_{F(AV)}$	Maximum Average Rectified Current @ $T_C = 130^\circ\text{C}$	10	A
I_{FSM}	Maximum Forward Surge Current (per diode) 60Hz Single Half-Sine Wave	80	A
T_J, T_{STG}	Operating Junction and Storage Temperature	-40 to +150	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case (per diode)	4.5	$^\circ\text{C}/\text{W}$

Electrical Characteristics (per diode) $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{FM}^*	Maximum Instantaneous Forward Voltage $I_F = 5\text{A}$ $I_F = 10\text{A}$	$T_C = 25^\circ\text{C}$	0.55
		$T_C = 125^\circ\text{C}$	0.49
		$T_C = 25^\circ\text{C}$	0.67
		$T_C = 125^\circ\text{C}$	0.65
I_{RM}^*	Maximum Instantaneous Reverse Current @ rated V_R	$T_C = 25^\circ\text{C}$	1
		$T_C = 125^\circ\text{C}$	40

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

Typical Characteristics

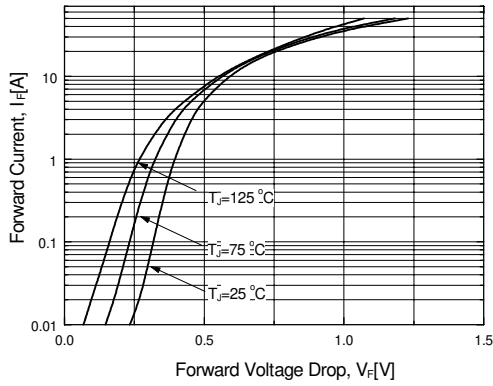


Figure 1. Typical Forward Voltage Characteristics (per diode)

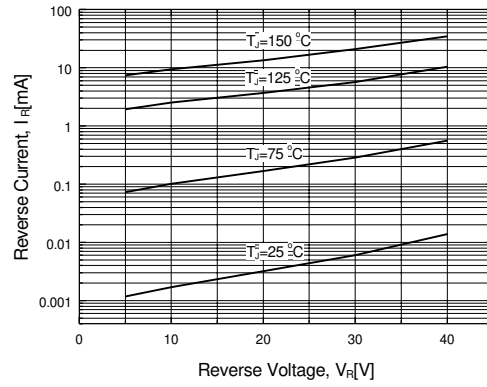


Figure 2. Typical Reverse Current vs. Reverse Voltage (per diode)

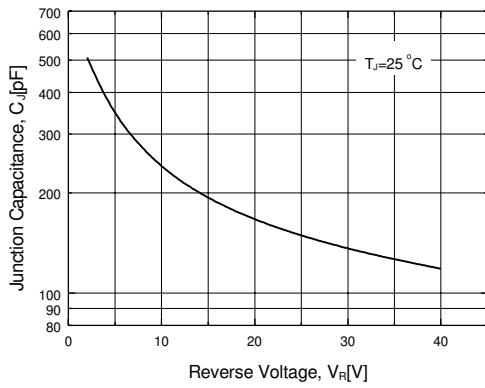


Figure 3. Typical Junction Capacitance (per diode)

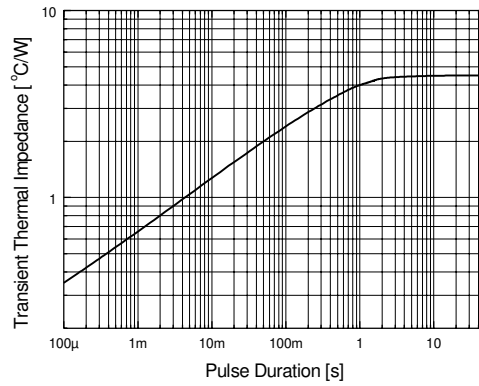


Figure 4. Thermal Impedance Characteristics (per diode)

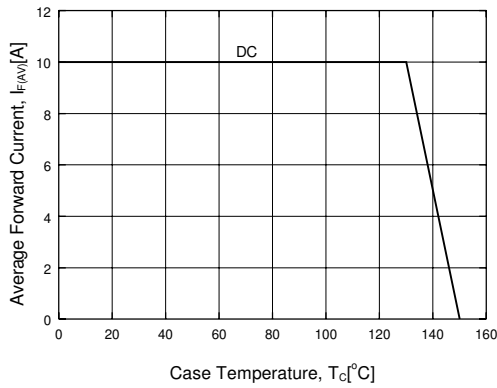


Figure 5. Forward Current Derating Curve

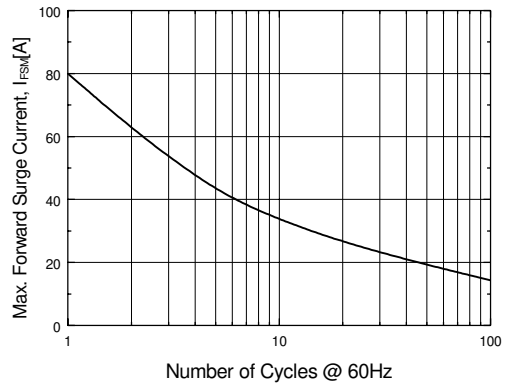
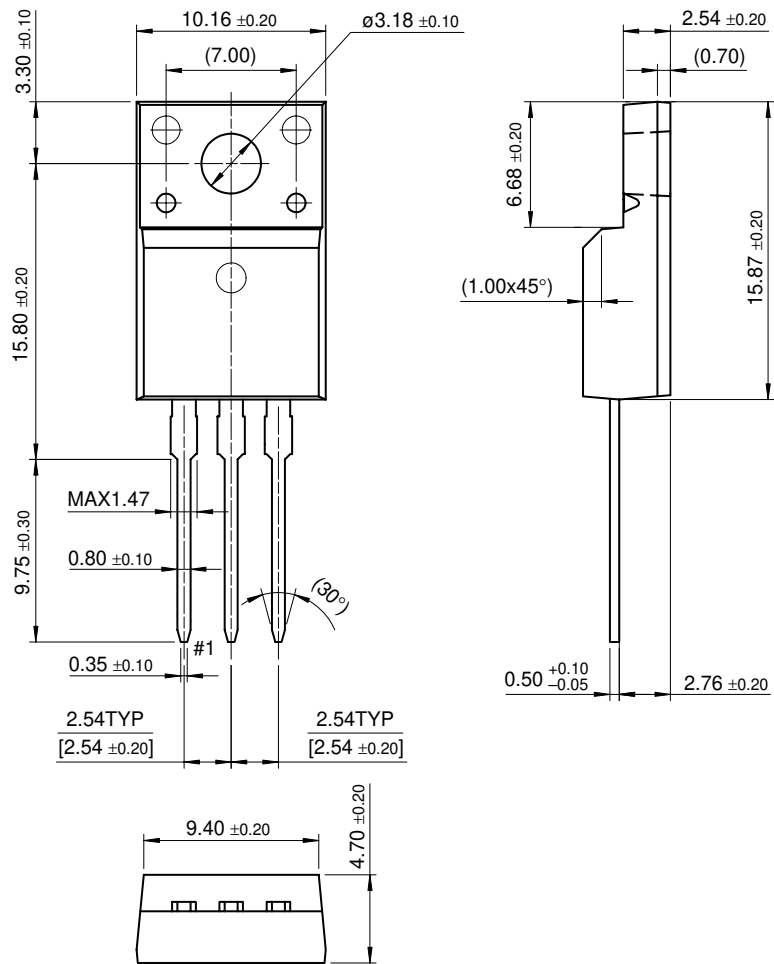


Figure 6. Non-Repetive Surge Current (per diode)

Package Dimensions

FYPF1004DN

TO-220F



Dimensions in Millimeters

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